



SBRT6U45LP

6A TrenchSBR TRENCH SUPER BARRIER RECTIFIER

Product Summary

V _{RRM} (V)	I _O (A)	V _F (MAX) (V) @ +25°C	I _{R(MAX)} (mA) @ +25°C
45	6	0.52	0.15

Features and Benefits

- Patented TrenchSBR technology provides superior avalanche capability versus Schottky diodes, ensuring more rugged and reliable end applications.
- Reduced ultra-low forward voltage drop (V_F); Better efficiency and cooler operation.
- Reduced high temperature reverse leakage; Increased reliability against thermal runaway failure in high temperature operation.
- Totally Lead-Free Finish & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Description and Applications

The SBRT6U45LP provides very low VF and excellent reverse leakage stability at high temperatures. It is ideal for use as bypass diode and rectifier, freewheel diode or blocking diode in applications such as:

- Solar Panels
- Blocking Diode
- Bypass Diode
- Boost Diode
- Recirculating Diode

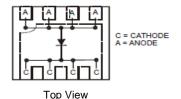
Mechanical Data

- Case:U-DFN3030-8
- Case Material: Molded Plastic, "Green" Molding Compound;
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208 63
- Polarity: See Below
- Weight: 0.0199 grams (Approximate)

U-DFN3030-8



Bottom View



Internal Schematic

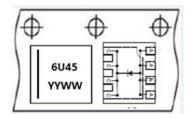
Ordering Information (Note 4)

Part Number	Case	Packaging
SBRT6U45LP-7	U-DFN3030-8	3,000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information





6U45 = Product Type Marking Code YYWW = Date Code Marking YY= Last Digit of Year (ex: 14 = 2014) WW = Week Code (ex: 01~53) Bar= Cathode



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load. For capacitance load, derate current by 20%.

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _{RM}	45	>
Average Rectified Output Current	lo	6	Α
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load	I _{FSM}	55	А

Thermal Characteristics

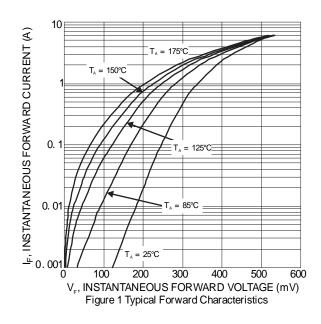
Characteristic		Symbol	Value	Unit
Typical Thermal Resistance Junction to Case (Note 5)		$R_{\theta JC}$	5.5	°C/W
Typical Thermal Resistance Junction to Ambient (Note 5)		$R_{\theta JA}$	65	°C/W
Operating Temperature Range VR ≤80% VRRM VR ≤50% VRRM DC Forward Mode (Note 7)		TJ	-55 to +150 ≤175 ≤+200	°C
Storage Temperature Range		T _{STG}	-55 to +150	°C

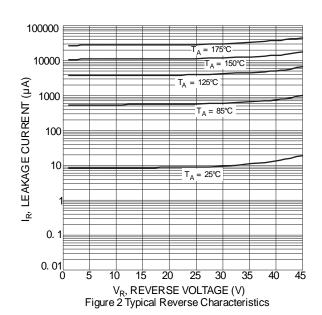
Electrical Characteristics (@ $T_A = \pm 25$ °C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Forward Voltage Drop (Note 6)	VF	_	_	0.52	V	I _F = 6A, T _J = +25°C
Leakage Current (Note 6)	1-	_	_	150	μΑ	V _R = 45V, T _J = +25°C
Leakage Current (Note 6)	IR	_	3.8	_	mA	$V_R = 45V, T_J = +125$ °C

Notes:

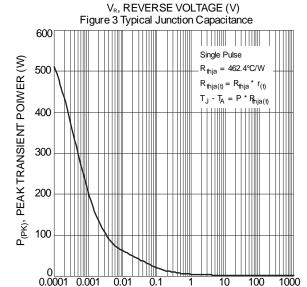
- 5. Device mounted on FR-4 PCB pad layout 1-inch 2oz copper.
- 6. Short duration pulse test used to minimize self-heating effect.
- 7. Max junction temperature guaranteed for two hours.







10000 TOUND TOUND



t1, PULSE DURATION TIME (sec) Figure 5 Single Pulse Maximum Power Dissipation

0.001

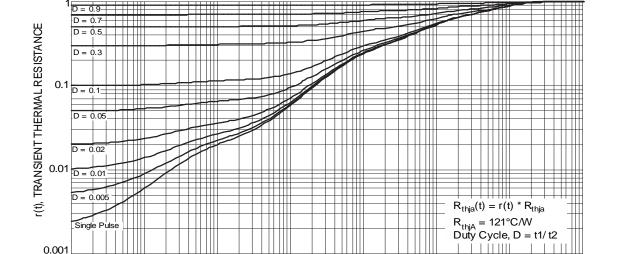
0.01

150
125 Note 5

125 Note 5

126 VR, DC REVERSE VOLTAGE (V)
Figure 4 Operating Temperature Derating

SBRT6U45LP



t1, PULSE DURATION TIME (sec) Figure 6 Transient Thermal Resistance

0.0001

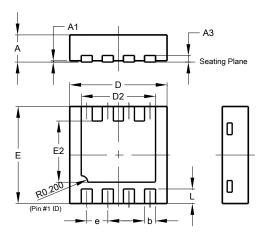
1000

100



Package Outline Dimensions

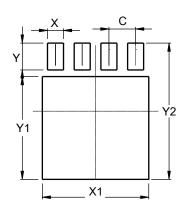
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



U-DFN3030-8				
Dim	Min	Max	Тур	
Α	0.57	0.63	0.60	
A1	0	0.05	0.02	
A3			0.15	
b	0.29	0.39	0.34	
D	2.90	3.10	3.00	
D2	2.19	2.39	2.29	
е		_	0.65	
E	2.90	3.10	3.00	
E2	1.64	1.84	1.74	
Ĺ	0.30	0.60	0.45	
All Dimensions in mm				

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value	
Dilliciisions	(in mm)	
С	0.650	
Х	0.390	
X1	2.590	
Υ	0.650	
Y1	2.490	
Y3	3.300	



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